

RJK2576DPA

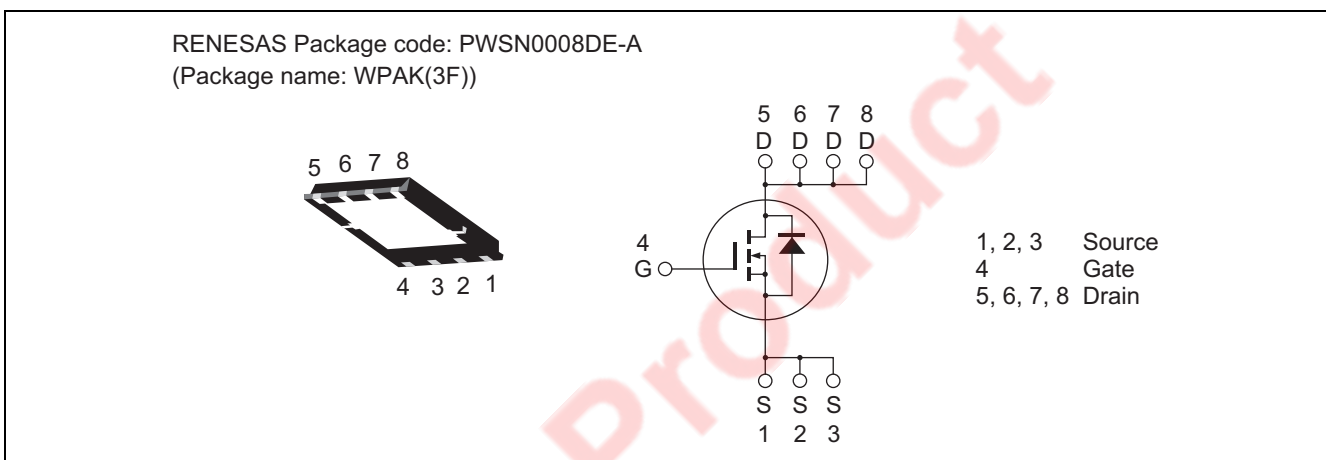
250V - 17A - MOS FET
High Speed Power Switching

R07DS0860EJ0200
Rev.2.00
Feb 05, 2013

Features

- Low on-resistance
 $R_{DS(on)} = 0.102 \Omega$ typ. (at $I_D = 8.5 \text{ A}$, $V_{GS} = 10 \text{ V}$, $T_a = 25^\circ\text{C}$)
- Very low gate charge
 $Q_g = 18 \text{ nC}$ typ. ($V_{DD} = 200 \text{ V}$, $V_{GS} = 10 \text{ V}$, $I_D = 17 \text{ A}$, $T_a = 25^\circ\text{C}$)
- Low leakage current
- High speed switching

Outline



Absolute Maximum Ratings

($T_a = 25^\circ\text{C}$)

Item	Symbol	Ratings	Unit
Drain to source voltage	V_{DSS}	250	V
Gate to source voltage	V_{GSS}	± 30	V
Drain current	I_D ^{Note4}	17	A
Drain peak current	$I_{D(pulse)}$ ^{Note1}	34	A
Body-drain diode reverse drain current	I_{DR}	17	A
Body-drain diode reverse drain peak current	$I_{DR(pulse)}$ ^{Note1}	34	A
Avalanche current	I_{AP} ^{Note2}	7	A
Avalanche energy	E_{AR} ^{Note2}	3	mJ
Channel dissipation	P_{ch} ^{Note3}	65	W
Channel to case thermal impedance	θ_{ch-c}	1.93	$^\circ\text{C}/\text{W}$
Channel temperature	T_{ch}	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

- Notes: 1. $PW \leq 10 \mu\text{s}$, duty cycle $\leq 1\%$
 2. $ST_{ch} = 25^\circ\text{C}$, $T_{ch} \leq 150^\circ\text{C}$
 3. Value at $T_c = 25^\circ\text{C}$
 4. Limited by maximum safe operation area

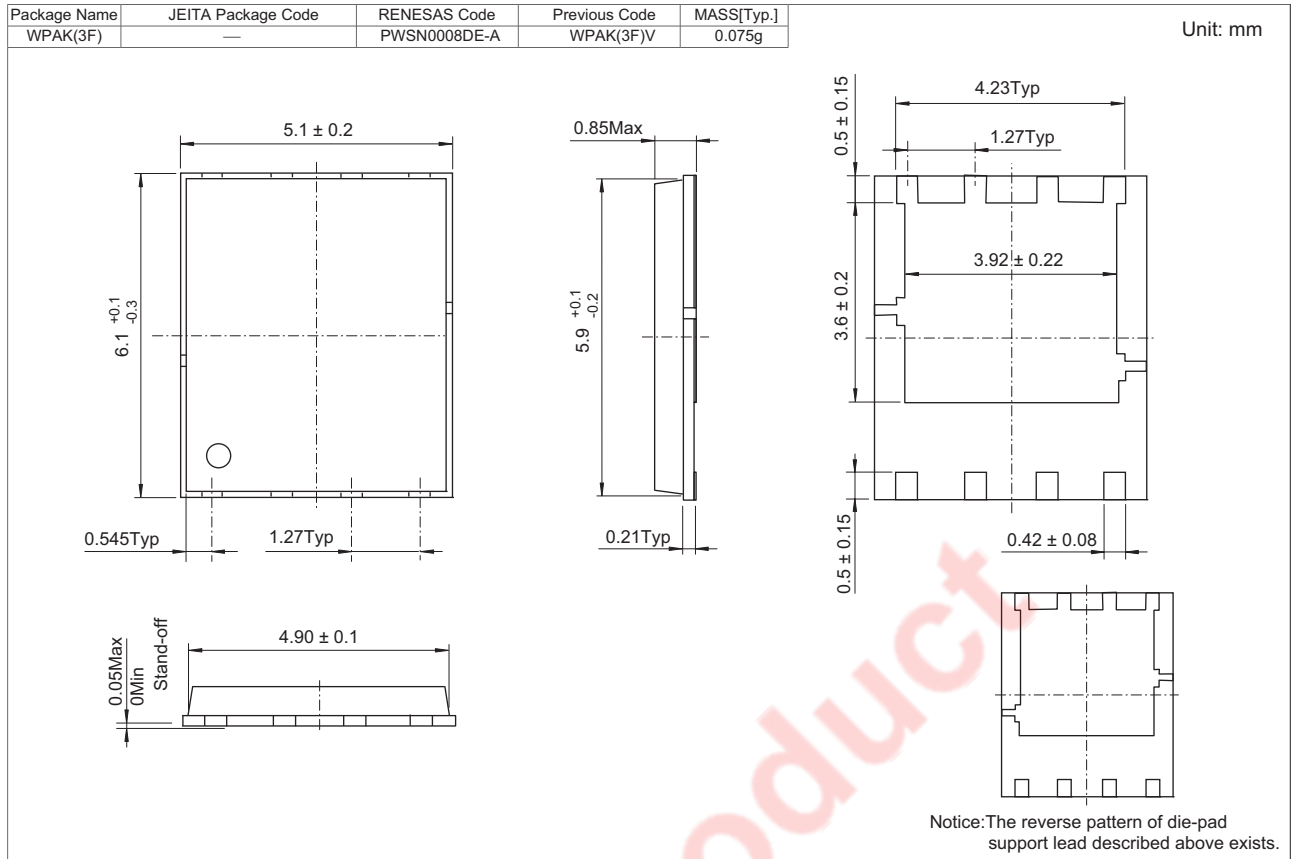
Electrical Characteristics

(Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	250	—	—	V	$I_D = 10 \text{ mA}$, $V_{GS} = 0$
Zero gate voltage drain current	I_{DSS}	—	—	1	μA	$V_{DS} = 250 \text{ V}$, $V_{GS} = 0$
Gate to source leak current	I_{GSS}	—	—	± 1	μA	$V_{GS} = \pm 30 \text{ V}$, $V_{DS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	2.5	—	4.5	V	$V_{DS} = 10 \text{ V}$, $I_D = 1 \text{ mA}$
Static drain to source on state resistance	$R_{DS(on)}$	—	0.102	0.128	Ω	$I_D = 8.5 \text{ A}$, $V_{GS} = 10 \text{ V}$ ^{Note5}
Input capacitance	C_{iss}	—	1200	—	pF	$V_{DS} = 25 \text{ V}$
Output capacitance	C_{oss}	—	165	—	pF	$V_{GS} = 0$
Reverse transfer capacitance	C_{rss}	—	18	—	pF	$f = 1 \text{ MHz}$
Turn-on delay time	$t_{d(on)}$	—	17	—	ns	$I_D = 8.93 \text{ A}$
Rise time	t_r	—	16	—	ns	$V_{GS} = 10 \text{ V}$
Turn-off delay time	$t_{d(off)}$	—	26	—	ns	$R_L = 14 \Omega$
Fall time	t_f	—	13	—	ns	$R_g = 10 \Omega$
Total gate charge	Q_g	—	18	—	nC	$V_{DD} = 200 \text{ V}$
Gate to source charge	Q_{gs}	—	6.5	—	nC	$V_{GS} = 10 \text{ V}$
Gate to drain charge	Q_{gd}	—	5	—	nC	$I_D = 17 \text{ A}$
Body-drain diode forward voltage	V_{DF}	—	0.81	1.35	V	$I_F = 17 \text{ A}$, $V_{GS} = 0$ ^{Note5}
Body-drain diode reverse recovery time	t_{rr}	—	113	—	ns	$I_F = 17 \text{ A}$, $V_{GS} = 0$ $di_F/dt = 100 \text{ A}/\mu\text{s}$

Notes: 5. Pulse test

Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJK2576DPA-00#J5A	3000 pcs	Taping

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